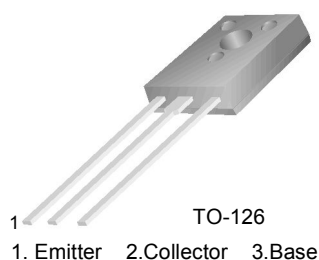


KSE13003 NPN Silicon Transistor

High Voltage Switch Mode Applications

- High Voltage Capability
- High Speed Switching
- Suitable for Switching Regulator and Motor Control



Absolute Maximum Ratings* T_C = 25°C unless otherwise noted (notes_1)

| Symbol | Parameter | Value | Units |
|------------------|---|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 700 | V |
| V _{CEO} | Collector-Emitter Voltage | 400 | V |
| V _{EBO} | Emitter-Base Voltage | 9 | V |
| I _C | Collector Current (DC) | 1.5 | A |
| I _{CP} | Collector Current (Pulse) | 3 | A |
| I _B | Base Current | 0.75 | A |
| P _C | Collector Dissipation (T _C = 25°C) | 20 | W |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature Range | -65 ~ 150 | °C |

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES_1:

1) These ratings are based on a maximum junction temperature of 150°C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

h_{FE} Classification

| Classification | H1 | H2 | H3 |
|-------------------|--------|--------|---------|
| h _{FE} * | 9 ~ 16 | 14~ 21 | 19 ~ 26 |

* Test on V_{CE} = 2V, I_C = 0.5A.

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Conditions | Min. | Typ. | Max | Units |
|---------------|---------------------------------------|---|--------|------|---------------|---------------|
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C = 5\text{mA}, I_B = 0$ | 400 | | | V |
| I_{EBO} | Emitter Cut-off Current | $V_{EB} = 9\text{V}, I_C = 0$ | | | 10 | μA |
| h_{FE} | *DC Current Gain | $V_{CE} = 2\text{V}, I_C = 0.5\text{A}$ $V_{CE} = 2\text{V}, I_C = 1\text{A}$ | 8 5 | | 40 | |
| $V_{CE(sat)}$ | *Collector Emitter Saturation Voltage | $I_C = 0.5\text{A}, I_B = 0.1\text{A}$ $I_C = 1\text{A}, I_B = 0.25\text{A}$ $I_C = 1.5\text{A}, I_B = 0.5\text{A}$ | | | 0.5 1 3 | V V V |
| $V_{BE(sat)}$ | *Base Emitter Saturation Voltage | $I_C = 0.5\text{A}, I_B = 0.1\text{A}$ $I_C = 1\text{A}, I_B = 0.25\text{A}$ | | | 1 1.2 | V V |
| C_{ob} | Output Capacitance | $V_{CB} = 10\text{V}, f = 0.1\text{MHz}$ | | 21 | | pF |
| f_T | Current Gain Bandwidth Product | $V_{CE} = 10\text{V}, I_C = 0.1\text{A}$ | 4 | | | MHz |
| t_{ON} | Turn On Time | $V_{CC} = 125\text{V}, I_C = 1\text{A}$ | | | 1.1 | ms |
| t_{STG} | Storage Time | $I_{B1} = 0.2\text{A}, I_{B2} = -0.2\text{A}$ $R_L = 125\text{W}$ | | | 4.0 | ms |
| t_F | Fall Time | | | | 0.7 | ms |

* Pulse Test: Pulse Width=5ms, Duty Cycle \leq 10%**Package Marking and Ordering Information**

| Device Item (notes_2) | Device Marking | Package | Packing Method | Remarks |
|-----------------------|----------------|---------|----------------|---------|
| KSE13003H1ASTU | 1 E13003 | TO-126 | TUBE | |
| KSE13003H2ASTU | 2 E13003 | TO-126 | TUBE | |
| KSE13003H3ASTU | 3 E13003 | TO-126 | TUBE | |

Notes_2 :

- 1) The Affix "-H1/-H2/-H3" means the h_{FE} classification.
- 2) The Suffix "-STU" means the TO126 short lead package and the Tube packing method, which can be on fairchildsemi website at <http://www.fairchildsemi.com>

Typical Performance Characteristics

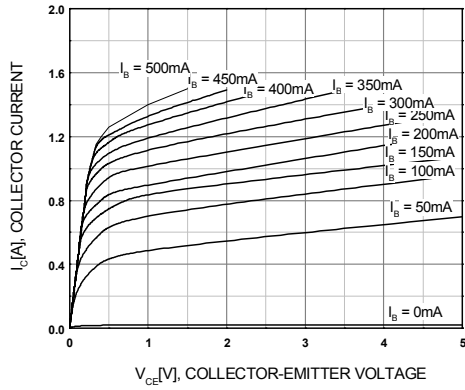


Figure 1. Static Characteristic

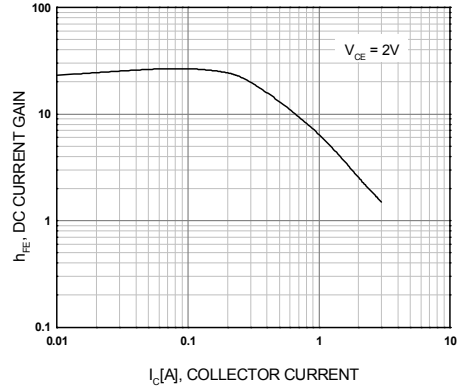


Figure 2. DC current Gain

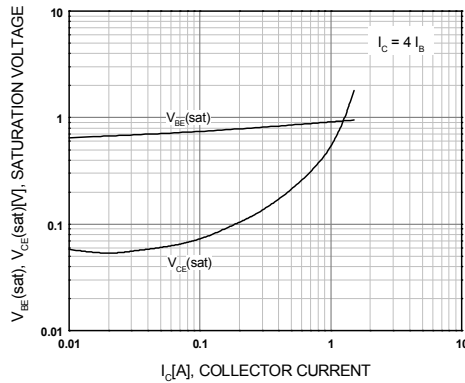


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

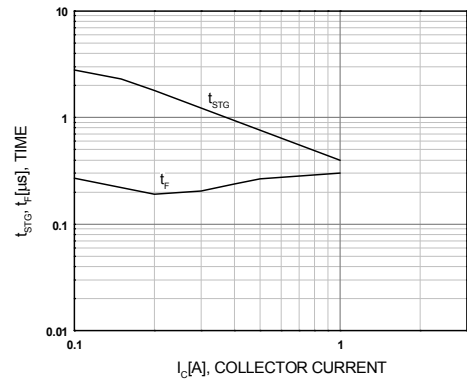


Figure 4. Switching Time

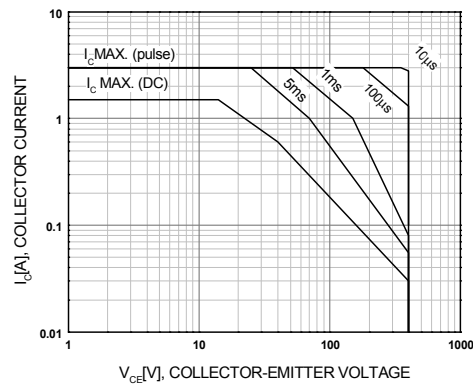


Figure 5. Safe Operating Area

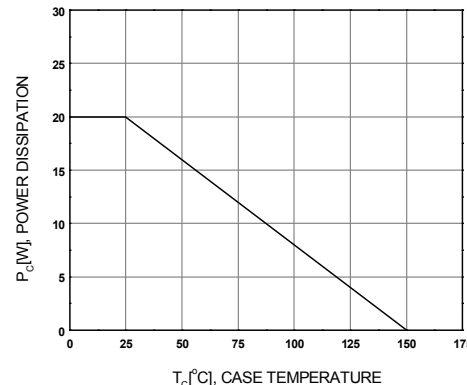







Figure 6. Power Derating



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

- | | | | |
|---|--|--|---|
| ACEX [®] | FPS [™] | PDP SPM [™] | The Power Franchise [®] |
| Build it Now [™] | F-PFST [™] | Power-SPM [™] |  |
| CorePLUS [™] | FRFET [®] | PowerTrench [®] | TinyBoost [™] |
| CorePOWER [™] | Global Power Resource SM | Programmable Active Droop [™] | TinyBuck [™] |
| CROSSVOLT [™] | Green FPS [™] | QFET [®] | TinyLogic [®] |
| CTL [™] | Green FPS [™] e-Series [™] | QS [™] | TINYOPTO [™] |
| Current Transfer Logic [™] | GTQ [™] | Quiet Series [™] | TinyPower [™] |
| EcoSPARK [®] | IntelliMAX [™] | RapidConfigure [™] | TinyPWM [™] |
| EfficientMax [™] | ISOPLANAR [™] | Saving our world, 1mW at a time [™] | TinyWire [™] |
| EZSWITCH [™] * | MegaBuck [™] | SmartMax [™] | μSerDes [™] |
|  | MICROCOUPLER [™] | SMART START [™] |  |
|  | MicroFET [™] | SPM [®] | UHC [®] |
| Fairchild [®] | MicroPak [™] | STEALTH [™] | Ultra FRFET [™] |
| Fairchild Semiconductor [®] | MillerDrive [™] | SuperFET [™] | UniFET [™] |
| FACT Quiet Series [™] | MotionMax [™] | SuperSOT [™] -3 | VCX [™] |
| FACT [®] | Motion-SPM [™] | SuperSOT [™] -6 | VisualMax [™] |
| FAST [®] | OPTOLOGIC [®] | SuperSOT [™] -8 | |
| FAST [®] | OPTOPLANAR [®] | SupreMOS [™] | |
| FastvCore [™] | | SyncFET [™] | |
| FlashWriter [®] * | |  | |

* EZSWITCH[™] and FlashWriter[®] are trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|-----------------------|--|
| Advance Information | Formative / In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. |
| Preliminary | First Production | This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. |
| No Identification Needed | Full Production | This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design. |
| Obsolete | Not In Production | This datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only. |

Rev. 134